UMA1N / FMA1A

PNP -100mA -50V Complex Digital Transistors (Bias Resistor Built-in Transistors) Datasheet

Parameter	Tr1 and Tr2
V _{CC}	-50V
I _{C(MAX.)}	-100mA
R ₁	$22k\Omega$
R_2	22k Ω

Features

- 1) Built-In Biasing Resistors, $R_1 = R_2 = 22k\Omega$.
- 2) Two DTA124E chips in one package.
- 3) Emitter(GND)-common type
- 4) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see inner circuit).
- 5) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of completely eliminating parasitic effects.
- 6) Only the on/off conditions need to be set for operation, making the circuit design easy.
- 7) Lead Free/RoHS Compliant.

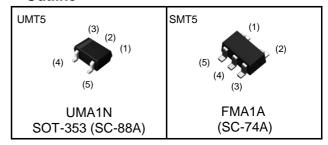
Application

Interface circuit, Driver circuit

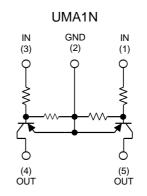
Packaging specifications

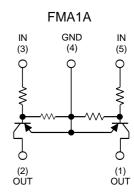
Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
UMA1N	UMT5	2021	TR	180	8	3,000	A1
FMA1A	SMT5	2928	T148	180	8	3,000	A1

Outline



•Inner circuit





● **Absolute maximum ratings** (Ta = 25°C)

<For Tr1 and Tr2 in common>

Parar	neter	Symbol	Values	Unit
Supply voltage		V _{CC}	–50	V
Input voltage		V _{IN}	-40 to +10	V
Output current		Io	-30	mA
Collector current		I _{C(MAX.)} *1	-100	mA
Power dissipation	wer dissipation UMA1N P _D *2		150 (Total) ^{*3}	mW
FMA1A		P _D	300 (Total) ^{*4}	mW
Junction temperature		T _j	150	°C
Range of storage temperature		T _{stg}	-55 to +150	°C

●Electrical characteristics(Ta = 25°C)

<For Tr1 and Tr2 in common>

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input voltage	$V_{I(off)}$	$V_{CC} = -5V, I_{O} = -100 \mu A$	ı	ı	-0.5	V
Input voltage	$V_{I(on)}$	$V_0 = -0.2V, I_0 = -5mA$	-3	-	-	V
Output voltage	$V_{O(on)}$	$I_0 / I_1 = -10 \text{mA} / -0.5 \text{mA}$	-	-0.1	-0.3	V
Input current	I _I	$V_1 = -5V$	-	-	-0.36	mA
Output current	I _{O(off)}	$V_{CC} = -50V, V_1 = 0V$	-	-	-0.5	μΑ
DC current gain	Gı	$V_0 = -5V, I_0 = -5mA$	56	-	-	-
Input resistance	R ₁	-	15.4	22	28.6	kΩ
Resistance ratio	R ₂ /R ₁	-	0.8	1	1.2	-
Transition frequency	f _T *1	$V_{CE} = -10V, I_{E} = 5mA,$ f = 100MHz	-	250	-	MHz

^{*1} Characteristics of built-in transistor

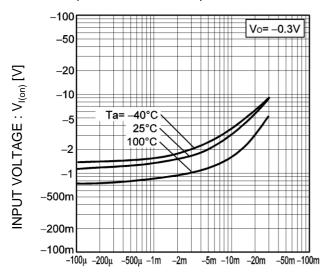
^{*2} Each terminal mounted on a reference footprint

^{*3 120}mW per element must not be exceeded.

^{*4 200}mW per element must not be exceeded.

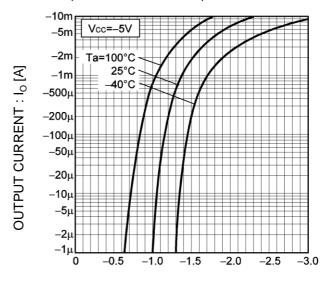
●Electrical characteristic curves(Ta = 25°C)

Fig.1 Input voltage vs. output current (ON characteristics)



OUTPUT CURRENT : Io [A]

Fig.2 Output current vs. input voltage (OFF characteristics)



INPUT VOLTAGE: V_{I(off)}[V]

Fig.3 Output current vs. output voltage

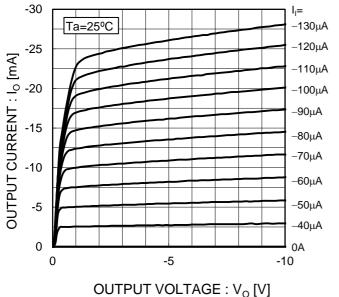
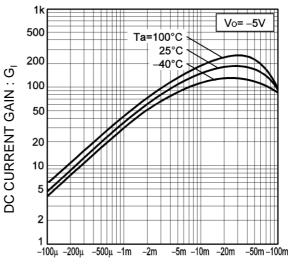


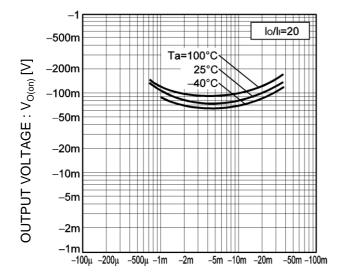
Fig.4 DC current gain vs. output current



OUTPUT CURRENT : Io [A]

●Electrical characteristic curves(Ta = 25°C)

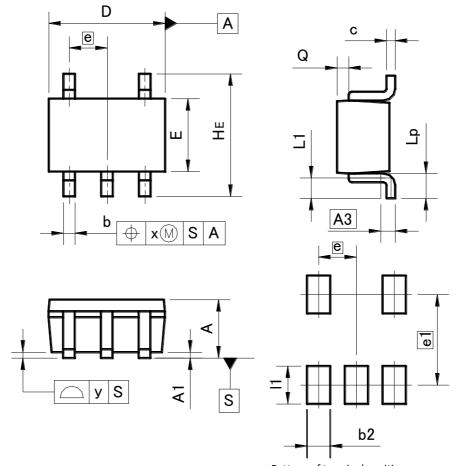
Fig.5 Output voltage vs. output current



OUTPUT CURRENT : I_O [A]

●Dimensions (Unit:mm)

UMT5



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

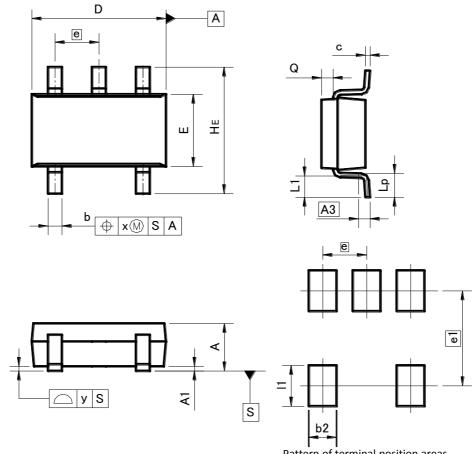
DIM	DIM MILIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	0.80	1.00	0.031	0.039
A1	0.00	0.10	0.000	0.004
A3	0.3	25	0.0	10
b	0.15	0.30	0.006	0.012
С	0.10	0.20	0.004	0.008
D	1.90	2.10	0.075	0.083
E	1.15	1.35	0.045	0.053
е	0.0	.65 0.026		26
HE	2.00	2.20	0.079	0.087
L1	0.20	0.50	0.008	0.020
Lp	0.25	0.55	0.010	0.022
Q	0.10	0.30	0.004	0.012
Х	_	0.10		0.004
У	_	0.10	_	0.004

DIM	MILIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
b2	_	0.40	ı	0.016
e1	1.	1.55		61
l1	_	0.65	-	0.026

Dimension in mm / inches

●Dimensions (Unit:mm)

SMT5



Pattern of terminal position areas
[Not a recommended pattern of soldering pads]

DIM MILIM		ETERS	INCHES	
DIM	MIN	MAX	MIN	MAX
Α	1.00	1.30	0.039	0.051
A1	0.00	0.10	0.000	0.004
A3	0.3	25	0.0	10
b	0.25	0.40	0.010	0.016
С	0.09	0.25	0.004	0.010
D	2.80	3.00	0.110	0.118
Е	1.50	1.80	0.059	0.071
е	0.9	0.95		37
HE	2.60	3.00	0.102	0.118
L1	0.30	0.60	0.012	0.024
Lp	0.40	0.70	0.016	0.028
Q	0.20	0.30	0.008	0.012
х	_	0.20	_	0.008
У	_	0.10	_	0.004

DIM	MILIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
b2	_	0.60	_	0.024	
e1	2.	10	0.083		
11	_	0.90	_	0.035	

Dimension in mm / inches

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